

# isc N-Channel MOSFET Transistor

# **AOB11S65**

### **FEATURES**

- Drain Current –I<sub>D</sub>=11A@ T<sub>C</sub>=25 °C
- Drain Source Voltage-
  - : V<sub>DSS</sub>=650V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 0.399 \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **DESCRIPTION**

• Designed for use in switch mode power supplies and general purpose applications.

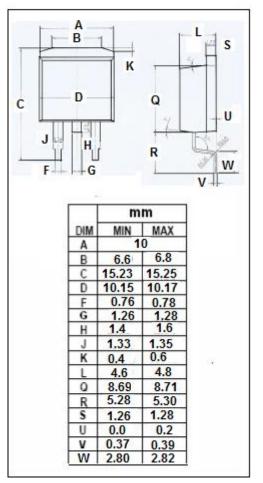
# Din 1.Gate 2.Drain 3.Source TO-263 package

# ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	650	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
I <sub>D</sub>	Drain Current-Continuous	11	А
I <sub>DM</sub>	Drain Current-Single Pluse	45	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	198	W
TJ	Max. Operating Junction Temperature -55~150		$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature -55~150		°C

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.63	°C/W



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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBO L	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	650			V
$V_{\text{GS}(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = 5V; I <sub>D</sub> = 0.25mA	2.6		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 5.5A			0.399	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0			1	μА
VsD	Forward On-Voltage	I <sub>S</sub> = 5.5A; V <sub>GS</sub> = 0		0.82		V

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